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Sheet _1 of _1

Form PTO-1449 (REV. 8-83))	US Dept. of Comme PATENT & TRADEMARK OFFI	rce CE	ATTY [125073	APPLICATION NO. New U.S. National Stage of			
INFORMATION DISCLOSURE STATEMENT					1	OT	548	009
(Use several sheets if necessary)				APPLICANT Simon DELEONIBUS				
					DATE 18, 2005			
		U.S	S. PATI	ENT DOC		<u> </u>		
EXAMINER INITIAL		DOCUMENT NUMBER		DATE	NAME		CLASS	SUB CLASS
دد	1)	US 6,451,657 B1	09/17/2002		GARDNER et al.			
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CC	3)	4,666,556	05/1	9/1987	FULTON et al.			
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در	6)	JP A 2002-134544 w/ abst. & trans	05/10/2002		JAPAN			
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CC	C C "Defect-free Si in Regrown Simox Structures,' Vol. 35, No. 3, pp. 60-61, August 1992							
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